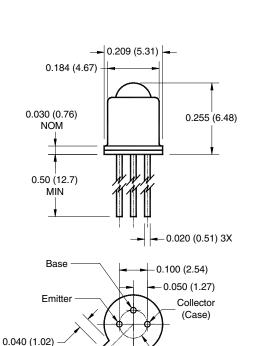
PACKAGE DIMENSIONS



NOTES:

0.040 (1.02)

- 1. Dimensions for all drawings are in inches (mm).
- 2. Tolerance of \pm .010 (.25) on all non-nominal dimensions unless otherwise specified.

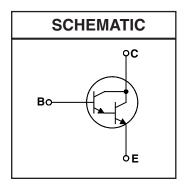
Ø0.100 (2.54)

FEATURES

- Hermetically sealed package
- · Narrow reception angle
- European "Pro Electron" registered

DESCRIPTION

 The BPW38 is a silicon photodarlington mounted in narrow angle TO-18 package.



- 1. Derate power dissipation linearly 3.00 mW/°C above 25°C ambient.
- 2. Derate power dissipation linearly 6.00 mW/°C above 25°C case.
- 3. RMA flux is recommended.
- 4. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 5. Soldering iron tip 1/16" (1.6mm) minimum from housing.
- 6. As long as leads are not under any stress or spring tension.
- Light source is a GaAs LED emitting light at a peak wavelength of 940 nm.

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise specified)							
Parameter	Symbol	Rating	Unit				
Operating Temperature	T _{OPR}	-65 to +125	°C				
Storage Temperature	T _{STG}	-65 to +150	°C				
Soldering Temperature (Iron)(3,4,5 and 6)	T _{SOL-I}	240 for 5 sec	°C				
Soldering Temperature (Flow)(3,4 and 6)	T _{SOL-F}	260 for 10 sec	°C				
Collector-Emitter Voltage	V _{CEO}	25	V				
Collector-Base Voltage	V _{CBO}	25	V				
Emitter-Base Voltage	V _{EBO}	12	V				
Power Dissipation (T _A = 25°C) ⁽¹⁾	P _D	300	mW				
Power Dissipation (T _C = 25°C) ⁽²⁾	Pn	600	mW				



ELECTRICAL / OPTICAL CHARACTERISTICS (TA =25°C) (All measurements made under pulse conditions)								
PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS		
Collector-Emitter Breakdown	$I_C = 10 \text{ mA}, Ee = 0$	BVceo	25	_	_	V		
Emitter-Base Breakdown	$I_E = 100 \mu A, Ee = 0$	ВУЕВО	12	_	_	V		
Collector-Base Breakdown	$I_C = 100 \mu A, Ee = 0$	ВУсво	25	_	_	V		
Collector-Emitter Leakage	$V_{CE} = 12 \text{ V, Ee} = 0$	ICEO	_	_	100	nA		
Reception Angle at 1/2 Sensitivity		θ	_	±8	_	Deg.		
On-State Collector Current	Ee = 0.125 mW/cm^2 $V_{CE} = 5 V^{(7)}$	Ic(on)	7.5	_	_	mA		
Rise Time	I_{C} = 10 mA, V_{CC} = 10 V R_{L} = 100 Ω	t _r	_	300	_	μs		
Fall Time	I_{C} = 10 mA, V_{CC} = 10 V R_{L} = 100 Ω	t _f	_	250	_	μs		

TYPICAL PERFORMANCE CURVES

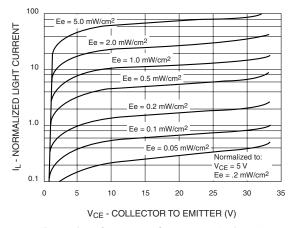


Fig. 1 Light Current vs. Collector to Emitter Voltage

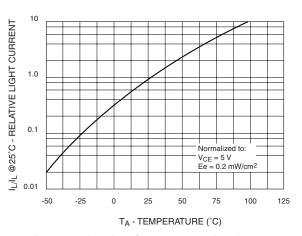


Fig. 2 Relative Light Current vs. Ambient Temperature



TYPICAL PERFORMANCE CURVES

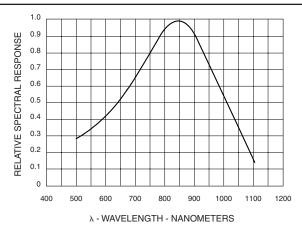


Fig. 3 Spectral Response Curve

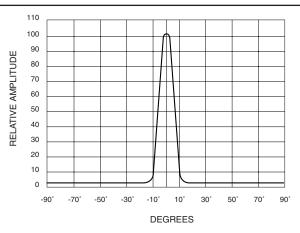


Fig. 4 Angular Response

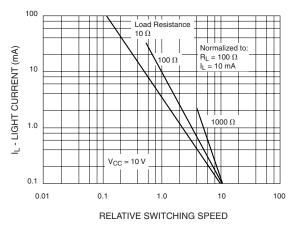


Fig. 5 Light Current vs. Relative Switching Speed

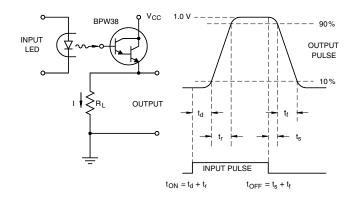


Fig. 6 Test Circuit and Voltage Waveforms



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- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.